

Solid State Relay OCMOS FET

PS7341-1A,PS7341L-1A

6-PIN DIP, HIGH ISOLATION VOLTAGE 1-ch Optical Coupled MOS FET

DESCRIPTION

The PS7341-1A and PS7341L-1A are solid state relays containing GaAs LEDs on the light emitting side (input side) and MOS FETs on the output side.

They are suitable for analog signal control because of their low offset and high linearity.

The PS7341L-1A has a surface mount type lead.

FEATURES

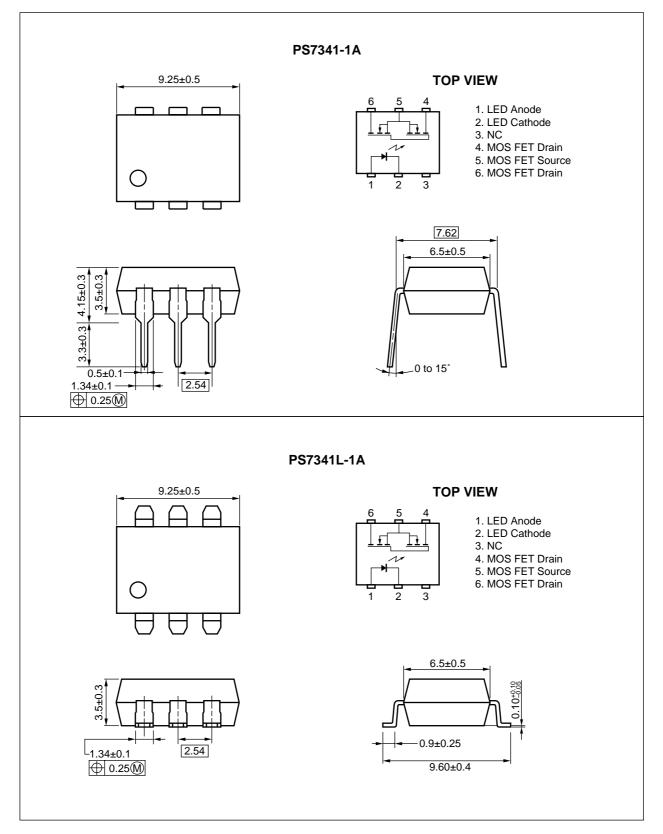
- High isolation voltage (BV = 3 750 Vr.m.s.)
- 1 channel type (1 a output)
- Low LED Operating Current (IF = 2 mA)
- Designed for AC/DC switching line changer
- Small package (6-pin DIP)
- · Low offset voltage
- PS7341L-1A: Surface mount type
- UL approved: File No. E72422 (S)
- BSI approved: No. 8252/8253
- CSA approved: No. CA 101391

APPLICATIONS

- Exchange equipment
- Measurement equipment
- FA/OA equipment

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

PACKAGE DIMENSIONS (in millimeters)



Part Number	Package	Packing Style	Application Part Number *1
PS7341-1A	6-pin DIP	Magazine case 50 pcs	PS7341-1A
PS7341L-1A			PS7341L-1A
PS7341L-1A-E3		Embossed Tape 1 000 pcs/reel	
PS7341L-1A-E4			

ORDERING INFORMATION (Solder Contains Lead)

*1 For the application of the Safety Standard, following part number should be used.

ORDERING INFORMATION (Pb-Free)

Part Number	Package	Packing Style	Application Part Number *1
PS7341-1A-A	6-pin DIP	Magazine case 50 pcs	PS7341-1A
PS7341L-1A-A			PS7341L-1A
PS7341L-1A-E3-A		Embossed Tape 1 000 pcs/reel	
PS7341L-1A-E4-A			

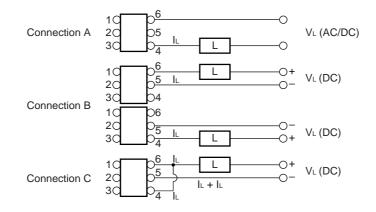
*1 For the application of the Safety Standard, following part number should be used.

Parameter			Symbol	Ratings	Unit
Diode	Forward Current (DC)		lf	50	mA
	Reverse Voltage		VR	5.0	V
	Power Dissipation		PD	50	mW
	Peak Forward Current ^{*1}		IFP	1	А
MOS FET	Break Down Voltage		VL	400	V
	Continuous Connection A		١L	150	mA
	Load Current ^{*2}	Connection B		200	
		Connection C		300	
	Pulse Load Current ^{*3} (AC/DC Connection)		Ilp	300	mA
	Power Dissipation		PD	560	mW
Isolation Voltage *4			BV	3 750	Vr.m.s.
Total Power Dissipation			Р⊤	610	mW
Operating Ambient Temperature			TA	-40 to +85	°C
Storage Temperature			Tstg	-40 to +125	°C

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise specified)

*1 PW = 100 µs, Duty Cycle = 1 %

*2 Conditions: IF \geq 2 mA. The following types of load connections are available.



*3 PW = 100 ms, 1 shot

*4 AC voltage for 1 minute at $T_A = 25$ °C, RH = 60 % between input and output

RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)

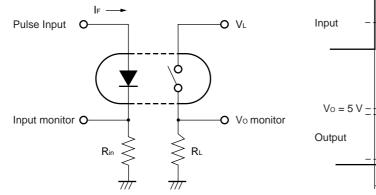
Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	lF	2	10	20	mA
LED Off Voltage	VF	0		0.5	V

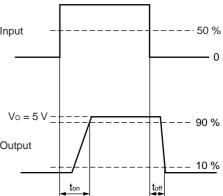
ELECTRICAL CHARACTERISTICS (TA = 25 °C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA		1.2	1.4	V
	Reverse Current	IR	V _R = 5 V			5.0	μA
MOS FET	Off-state Leakage Current	Loff	Vp = 400 V		0.03	1.0	μA
	Output Capacitance	Cout	V _D = 0 V, f = 1 MHz		65		pF
Coupled	LED On-state Current	IFon	l∟ = 150 mA			2.0	mA
	On-state Resistance	Ron1	I⊧ = 10 mA, I∟ = 10 mA		20	30	Ω
		Ron2	I_{F} = 10 mA, I_{L} = 150 mA, $t \leq$ 10 ms		16	25	
	Turn-on Time ^{*1}	ton	$I_F = 10 \text{ mA}, \text{ Vo} = 5 \text{ V}, \text{ RL} = 2 \text{ k}\Omega,$		0.35	1.0	ms
	Turn-off Time *1	toff	PW ≥ 10 ms		0.03	0.2	
	Isolation Resistance	R ⊦o	VI-O = 1.0 kVDC	10 ⁹			Ω
	Isolation Capacitance	CI-O	V = 0 V, f = 1 MHz		1.1		pF

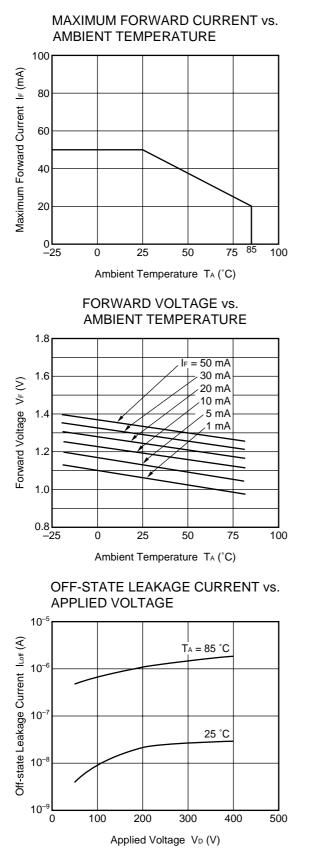
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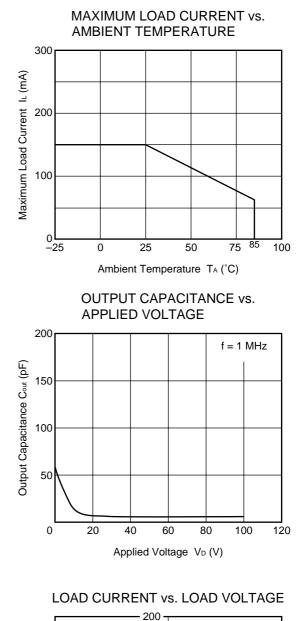
*1 Test Circuit for Switching Time

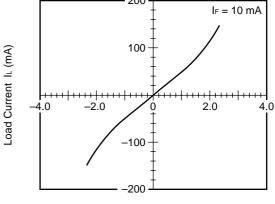




★ TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise specified)

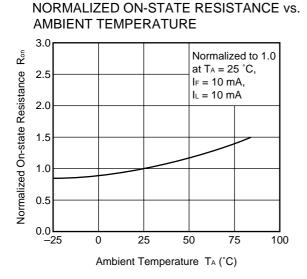




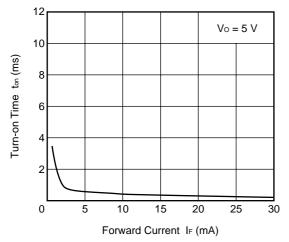


Load Voltage $V_{L}(V)$

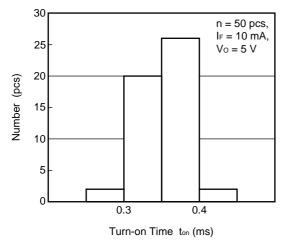
Data Sheet PN10306EJ01V1DS



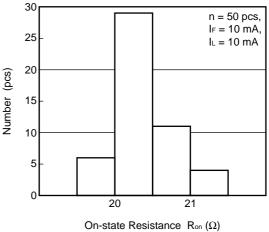
TURN-ON TIME vs. FORWARD CURRENT



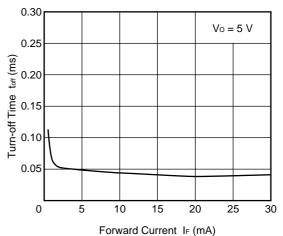
TURN-ON TIME DISTRIBUTION



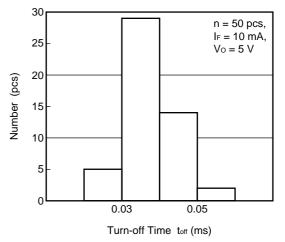
ON-STATE RESISTANCE DISTRIBUTION

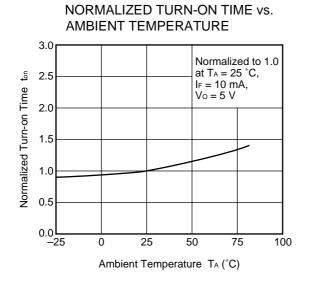


TURN-OFF TIME vs. FORWARD CURRENT

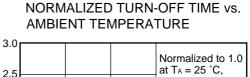


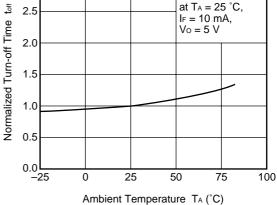
TURN-OFF TIME DISTRIBUTION



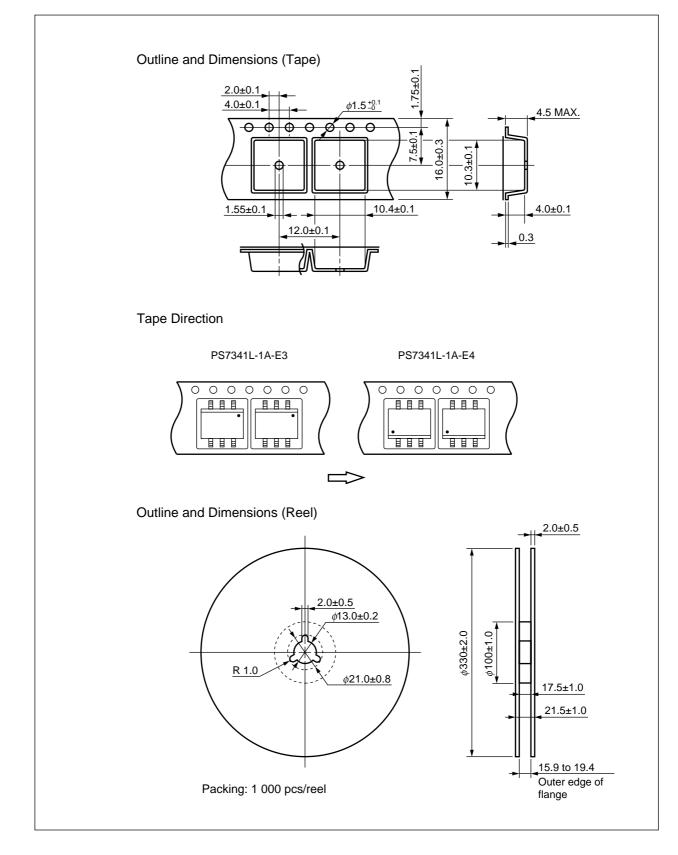


Remark The graphs indicate nominal characteristics.





* TAPING SPECIFICATIONS (in millimeters)



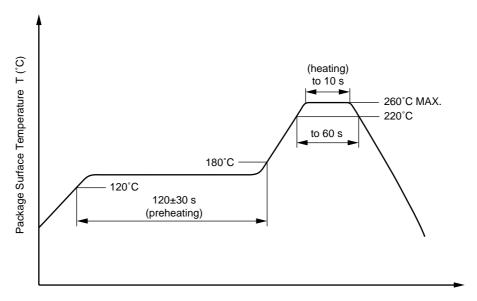
★ RECOMMENDED SOLDERING CONDITIONS

- (1) Infrared reflow soldering
 - Peak reflow temperature
 - Time of peak reflow temperature
 - Time of temperature higher than 220°C
 - Time to preheat temperature from 120 to 180°C
 - Number of reflows
 - Flux

260°C or below (package surface temperature) 10 seconds or less 60 seconds or less 120±30 s Two Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times
 One
- Flux

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Cautions

• Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.



Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices		
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)	
Mercury	< 1000 PPM	Not Detected		
Cadmium	< 100 PPM	Not Detected		
Hexavalent Chromium	< 1000 PPM	Not Detected		
РВВ	< 1000 PPM	Not Detected		
PBDE	< 1000 PPM	Not Detected		

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

In no event shall CEL's liability arising out of such information exceed the total purchase price of the CEL part(s) at issue sold by CEL to customer on an annual basis.

See CEL Terms and Conditions for additional clarification of warranties and liability.

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